

FEATURES

Enhanced system-level ESD performance per IEC 61000-4-x

High temperature operation: 125°C

Narrow body, RoHS-compliant, 8-lead SOIC

Low power operation

5 V operation

1.7 mA per channel maximum at 0 Mbps to 2 Mbps

3.7 mA per channel maximum at 10 Mbps

7.0 mA per channel maximum at 25 Mbps

3.3 V operation

1.5 mA per channel maximum at 0 Mbps to 2 Mbps

2.5 mA per channel maximum at 10 Mbps

5.2 mA per channel maximum at 25 Mbps

Bidirectional communication

3.3 V/5 V level translation

High data rate: dc to 25 Mbps (NRZ)

Precise timing characteristics

3 ns maximum pulse width distortion

3 ns maximum channel-to-channel matching

High common-mode transient immunity: >25 kV/μs

Safety and regulatory approvals

UL recognition: 2500 V rms for 1 minute per UL 1577

CSA Component Acceptance Notice 5A

VDE Certificate of Conformity

DIN V VDE V 0884-10 (VDE V 0884-10): 2006-12

$V_{IORM} = 560$ V peak

Qualified for automotive applications

APPLICATIONS

Size-critical multichannel isolation

SPI interface/data converter isolation

RS-232/RS-422/RS-485 transceiver isolation

Digital field bus isolation

Hybrid electric vehicles, battery monitor

GENERAL DESCRIPTION

The ADuM3200/ADuM3201¹ are dual-channel, digital isolators based on the Analog Devices, Inc., *iCoupler*® technology. Combining high speed CMOS and monolithic transformer technology, these isolation components provide outstanding performance characteristics superior to alternatives such as optocoupler devices.

By avoiding the use of LEDs and photodiodes, *iCoupler* devices remove the design difficulties commonly associated with optocouplers. The typical optocoupler concerns regarding uncertain current transfer ratios, nonlinear transfer functions, and temperature and lifetime effects are eliminated with the simple *iCoupler* digital interfaces and stable performance characteristics. The need for external drivers and other discrete components is eliminated with these *iCoupler* products. Furthermore, *iCoupler* devices consume one-tenth to one-sixth the power of optocouplers at comparable signal data rates.

The ADuM3200/ADuM3201 isolators provide two independent isolation channels in a variety of channel configurations and data rates (see the Ordering Guide). They operate with 3.3 V or 5 V supply voltages on either side, providing compatibility with lower voltage systems as well as enabling voltage translation functionality across the isolation barrier. The ADuM3200W and ADuM3201W are automotive grade versions qualified for 125°C operation.

In comparison to the ADuM1200/ADuM1201 isolators, the ADuM3200/ADuM3201 isolators contain various circuit and layout changes to provide increased capability relative to system-level IEC 61000-4-x testing (ESD, burst, and surge). The precise capability in these tests for either the ADuM1200/ADuM1201 or ADuM3200/ADuM3201 products is strongly determined by the design and layout of the user board or module. For more information, see the AN-793 Application Note, *ESD/Latch-Up Considerations with iCoupler Isolation Products*.

FUNCTIONAL BLOCK DIAGRAMS



Figure 1. ADuM3200 Functional Block Diagram



Figure 2. ADuM3201 Functional Block Diagram

¹ Protected by U.S. Patents 5,952,849; 6,873,065; 7,075,329.

Rev. F

[Document Feedback](#)

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

TABLE OF CONTENTS

| | | | |
|---|----|--|----|
| Features | 1 | Insulation and Safety-Related Specifications..... | 12 |
| Applications..... | 1 | DIN V VDE V 0884-10 (VDE V 0884-10) Insulation | |
| General Description | 1 | Characteristics | 13 |
| Functional Block Diagrams..... | 1 | Recommended Operating Conditions | 13 |
| Revision History | 3 | Absolute Maximum Ratings | 14 |
| Specifications..... | 4 | ESD Caution..... | 14 |
| Electrical Characteristics—5 V, 105°C Operation | 4 | Pin Configurations and Function Descriptions | 15 |
| Electrical Characteristics—3.3 V, 105°C Operation | 5 | Typical Performance Characteristics | 16 |
| Electrical Characteristics—Mixed 5 V/3.3 V, 105°C | | Application Information..... | 17 |
| Operation..... | 6 | PC Board Layout | 17 |
| Electrical Characteristics—Mixed 3.3 V/5 V, 105°C | | System-Level ESD Considerations and Enhancements | 17 |
| Operation..... | 7 | Propagation Delay-Related Parameters..... | 17 |
| Electrical Characteristics—5 V, 125°C Operation | 8 | DC Correctness and Magnetic Field Immunity..... | 17 |
| Electrical Characteristics—3.3 V, 125°C Operation | 9 | Power Consumption | 19 |
| Electrical Characteristics—Mixed 5 V/3.3 V, 125°C | | Insulation Lifetime | 19 |
| Operation..... | 10 | Outline Dimensions | 20 |
| Electrical Characteristics—Mixed 3.3 V/5 V, 125°C | | Ordering Guide | 21 |
| Operation..... | 11 | Automotive Products..... | 21 |
| Package Characteristics | 12 | | |
| Regulatory Information..... | 12 | | |

REVISION HISTORY**5/2016—Rev. E to Rev. F**

| | |
|--|----|
| Change to Logic High Output Voltages Parameter and Logic Low Output Voltages Parameter, Table 3 | 4 |
| Change to Logic High Output Voltages Parameter and Logic Low Output Voltages Parameter, Table 6 | 5 |
| Change to Logic High Output Voltages Parameter and Logic Low Output Voltages Parameter, Table 9 | 6 |
| Change to Logic High Output Voltages Parameter and Logic Low Output Voltages Parameter, Table 12 | 7 |
| Change to Logic High Output Voltages Parameter and Logic Low Output Voltages Parameter, Table 15 | 8 |
| Change to Logic High Output Voltages Parameter and Logic Low Output Voltages Parameter, Table 18 | 9 |
| Change to Logic High Output Voltages Parameter and Logic Low Output Voltages Parameter, Table 21 | 10 |
| Change to Logic High Output Voltages Parameter and Logic Low Output Voltages Parameter, Table 24 | 11 |

7/2015—Rev. D to Rev. E

| | |
|---|----|
| Changed ADuM120x to ADuM1200/ADuM1201... Throughout | |
| Changes to Logic High Output Voltages Parameter, Table 3 | 4 |
| Changes to Logic High Output Voltages Parameter, Table 6 | 5 |
| Change to Logic Low Input Threshold Parameter, Table 9 | 6 |
| Change to Logic Low Input Threshold Parameter, Table 12 | 7 |
| Changes to Logic High Output Voltages Parameter, Table 15 | 8 |
| Changes to Logic High Output Voltages Parameter, Table 18 | 9 |
| Change to Logic Low Input Threshold Parameter, Table 21 | 10 |
| Change to Logic Low Input Threshold Parameter, Table 24 | 11 |
| Changes to Table 26 and Table 27 | 12 |
| Changes to Ordering Guide..... | 21 |

10/2014—Rev. C to Rev. D

| | |
|--|----|
| Changed Low Voltage Operation from 3 V to 3.3 V (Throughout) | 1 |
| Changes to Features Section | 1 |
| Changes to Table 2 | 3 |
| Changes to Table 5 | 4 |
| Changes to Table 8 | 5 |
| Changes to Table 11 | 6 |
| Specified W Grade in Table 13 and Table 14 | 7 |
| Specified W Grade in Table 16 and Table 17 | 8 |
| Specified W Grade in Table 19 and Table 20 | 9 |
| Specified W Grade in Table 22 and Table 23 | 10 |
| Changes to Table 29 | 12 |

2/2012—Rev. B to Rev. C

| | |
|---|----|
| Created Hyperlink for Safety and Regulatory Approvals Entry in Features Section | 1 |
| Change to PC Board Layout Section | 16 |

11/2011—Rev. A to Rev. B

| | |
|---|----|
| Changes to Features Section, Applications Section, and General Descriptions Section | 1 |
| Changes to Specifications Section | 3 |
| Changes to Table 29 | 12 |
| Changes to Ambient Operating Temperature Maximum Value, Table 30 | 13 |
| Changes to V _{DD1} Pin Descriptions | 14 |
| Changes to Figure 9, Figure 10, Figure 11 Captions | 15 |
| Changes to Ordering Guide | 20 |
| Added Automotive Products Section | 20 |

6/2007—Rev. 0 to Rev. A

| | |
|---|----|
| Updated VDE Certification Throughout..... | 1 |
| Changes to Features, General Description, and Note 1 | 1 |
| Changes to Regulatory Information Section..... | 10 |
| Changes to DIN V VDE V 0884-10 (VDE V 0884-10) Insulation Characteristics Section | 11 |
| Added Table 10 | 12 |
| Added Insulation Lifetime Section | 17 |

7/2006—Revision 0: Initial Version

SPECIFICATIONS

ELECTRICAL CHARACTERISTICS—5 V, 105°C OPERATION

All typical specifications are at $T_A = 25^\circ\text{C}$, $V_{DD1} = V_{DD2} = 5\text{ V}$. Minimum/maximum specifications apply over the entire recommended operation range: $4.5\text{ V} \leq V_{DD1} \leq 5.5\text{ V}$, $4.5\text{ V} \leq V_{DD2} \leq 5.5\text{ V}$, and $-40^\circ\text{C} \leq T_A \leq +105^\circ\text{C}$, unless otherwise noted. Switching specifications are tested with $C_L = 15\text{ pF}$ and CMOS signal levels, unless otherwise noted.

Table 1.

| Parameter | Symbol | A Grade | | | B Grade | | | C Grade | | | Unit | Test Conditions/Comments |
|--------------------------|--------------------|---------|-----|-----|---------|-----|-----|---------|-----|-----|-------|--------------------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | |
| SWITCHING SPECIFICATIONS | | | | | | | | | | | | |
| Data Rate | | | | 1 | | 10 | | | 25 | | Mbps | Within PWD limit |
| Propagation Delay | t_{PHL}, t_{PLH} | 20 | | 150 | 20 | 50 | 20 | | 45 | | ns | 50% input to 50% output |
| Pulse Width Distortion | PWD | | | 40 | | 3 | | | 3 | | ns | $ t_{PLH} - t_{PHL} $ |
| Change vs. Temperature | | | 6 | | | 5 | | 5 | | | ps/°C | |
| Pulse Width | PW | 1000 | | | 100 | | | 40 | | | ns | Within PWD limit |
| Propagation Delay Skew | t_{PSK} | | | 100 | | 15 | | | 15 | | ns | Between any two units |
| Channel Matching | | | | | | | | | | | | |
| Codirectional | t_{PSKCD} | | | 50 | | 3 | | | 3 | | ns | |
| Opposing-Direction | t_{PSKOD} | | | 50 | | 15 | | | 15 | | ns | |
| Output Rise/Fall Time | t_R/t_F | | 10 | | | 2.5 | | | 2.5 | | ns | 10% to 90% |

Table 2.

| Parameter | Symbol | 1 Mbps—A Grade, B Grade, and C Grade | | | 10 Mbps—B Grade and C Grade | | | 25 Mbps—C Grade | | | Unit | Test Conditions/Comments | |
|----------------|-----------|--------------------------------------|-----|-----|-----------------------------|-----|-----|-----------------|-----|------|------|--------------------------|---------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | | |
| SUPPLY CURRENT | | | | | | | | | | | | | |
| ADuM3200 | I_{DD1} | | 1.3 | 1.8 | | 3.5 | 4.6 | | 7.7 | 10.0 | | mA | No load |
| | I_{DD2} | | 1.0 | 1.6 | | 2.0 | 2.8 | | 3.8 | 4.9 | | mA | No load |
| ADuM3201 | I_{DD1} | | 1.1 | 1.6 | | 3.1 | 4.2 | | 6.9 | 8.9 | | mA | No load |
| | I_{DD2} | | 1.3 | 1.9 | | 3.1 | 4.0 | | 6.1 | 8.3 | | mA | No load |

Table 3. For All Models

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
|---|--------------|-----------------|-----------------|-----|-------------------|---|
| DC SPECIFICATIONS | | | | | | |
| Logic High Input Threshold | V_{IH} | $0.7 V_{DDx}$ | | | V | |
| Logic Low Input Threshold | V_{IL} | | | | $0.3 V_{DDx}$ | |
| Logic High Output Voltages | V_{OH} | $V_{DDx} - 0.1$ | V_{DDx} | | V | $I_{Ox} = -20\ \mu\text{A}$, $V_{Ix} = V_{IxH}$ |
| | | $V_{DDx} - 0.5$ | $V_{DDx} - 0.2$ | | V | $I_{Ox} = -3.2\ \text{mA}$, $V_{Ix} = V_{IxH}$ |
| Logic Low Output Voltages | V_{OL} | | 0.0 | 0.1 | V | $I_{Ox} = 20\ \mu\text{A}$, $V_{Ix} = V_{IxL}$ |
| | | | 0.2 | 0.4 | V | $I_{Ox} = 3.2\ \text{mA}$, $V_{Ix} = V_{IxL}$ |
| Input Current per Channel | I_i | -10 | +0.01 | +10 | μA | $0\text{ V} \leq V_{Ix} \leq V_{DDx}$ |
| Supply Current per Channel | | | | | | |
| Quiescent Input Supply Current | $I_{DD1(Q)}$ | | 0.4 | 0.8 | mA | $V_{IA} = V_{IB} = 0\text{ V}$ |
| Quiescent Output Supply Current | $I_{DD2(Q)}$ | | 0.5 | 0.6 | mA | $V_{IA} = V_{IB} = 0\text{ V}$ |
| Dynamic Input Supply Current | $I_{DD1(D)}$ | | 0.19 | | mA/Mbps | |
| Dynamic Output Supply Current | $I_{DD2(D)}$ | | 0.05 | | mA/Mbps | |
| AC SPECIFICATIONS | | | | | | |
| Common-Mode Transient Immunity ¹ | $ CM $ | 25 | 35 | | kV/ μs | $V_{Ix} = V_{DDx}$, $V_{CM} = 1000\text{ V}$, transient magnitude = 800 V |
| Refresh Rate | f_r | | 1.2 | | Mbps | |

¹ $|CM|$ is the maximum common-mode voltage slew rate that can be sustained while maintaining $V_o > 0.8 V_{DD}$. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges.

ELECTRICAL CHARACTERISTICS—3.3 V, 105°C OPERATION

All typical specifications are at $T_A = 25^\circ\text{C}$, $V_{DD1} = V_{DD2} = 3.3\text{ V}$. Minimum/maximum specifications apply over the entire recommended operation range: $3.0\text{ V} \leq V_{DD1} \leq 3.6\text{ V}$, $3.0\text{ V} \leq V_{DD2} \leq 3.6\text{ V}$, and $-40^\circ\text{C} \leq T_A \leq +105^\circ\text{C}$, unless otherwise noted. Switching specifications are tested with $C_L = 15\text{ pF}$ and CMOS signal levels, unless otherwise noted.

Table 4.

| Parameter | Symbol | A Grade | | | B Grade | | | C Grade | | | Unit | Test Conditions/Comments |
|--------------------------|--------------------|---------|-----|-----|---------|-----|-----|---------|-----|-----|-------|--------------------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | |
| SWITCHING SPECIFICATIONS | | | | | | | | | | | | |
| Data Rate | | | | 1 | | | 10 | | | 25 | Mbps | Within PWD limit |
| Propagation Delay | t_{PHL}, t_{PLH} | 20 | | 150 | 20 | | 60 | 20 | | 55 | ns | 50% input to 50% output |
| Pulse Width Distortion | PWD | | | | | | | | | | | |
| ADuM3200 | | | | 40 | | | 3 | | | 3 | ns | $ t_{PLH} - t_{PHL} $ |
| ADuM3201 | | | | 40 | | | 4 | | | 4 | ns | $ t_{PLH} - t_{PHL} $ |
| Change vs. Temperature | | | 6 | | | 5 | | | 5 | | ps/°C | |
| Pulse Width | PW | 1000 | | | 100 | | | 40 | | | ns | Within PWD limit |
| Propagation Delay Skew | t_{PSK} | | | 100 | | | 22 | | | 16 | ns | Between any two units |
| Channel Matching | | | | | | | | | | | | |
| Codirectional | t_{PSKCD} | | | 50 | | | 3 | | | 3 | ns | |
| Opposing-Direction | t_{PSKOD} | | | 50 | | | 22 | | | 16 | ns | |
| Output Rise/Fall Time | t_R/t_F | | 3.0 | | | 3.0 | | | 3.0 | | ns | 10% to 90% |

Table 5.

| Parameter | Symbol | 1 Mbps—A Grade, B Grade, and C Grade | | | 10 Mbps—B Grade and C Grade | | | 25 Mbps—C Grade | | | Unit | Test Conditions/Comments |
|----------------|-----------|--------------------------------------|-----|-----|-----------------------------|-----|-----|-----------------|-----|-----|------|--------------------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | |
| SUPPLY CURRENT | | | | | | | | | | | | |
| ADuM3200 | I_{DD1} | 0.8 | 1.3 | | 2.2 | 3.2 | | 4.8 | 6.4 | | mA | No load |
| | I_{DD2} | 0.7 | 1.0 | | 1.3 | 1.7 | | 2.3 | 3.0 | | mA | No load |
| ADuM3201 | I_{DD1} | 0.7 | 1.3 | | 1.9 | 2.5 | | 4.1 | 5.3 | | mA | No load |
| | I_{DD2} | 0.8 | 1.6 | | 1.9 | 2.5 | | 3.7 | 5.1 | | mA | No load |

Table 6. For All Models

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
|---|--------------|-----------------|-----------------|-----|-------------------|---|
| DC SPECIFICATIONS | | | | | | |
| Logic High Input Threshold | V_{IH} | $0.7 V_{DDx}$ | | | V | |
| Logic Low Input Threshold | V_{IL} | | | | $0.3 V_{DDx}$ | V |
| Logic High Output Voltages | V_{OH} | $V_{DDx} - 0.1$ | V_{DDx} | | V | $I_{Ox} = -20\ \mu\text{A}$, $V_{Ix} = V_{IxH}$ |
| | | $V_{DDx} - 0.5$ | $V_{DDx} - 0.2$ | | V | $I_{Ox} = -3.2\ \text{mA}$, $V_{Ix} = V_{IxH}$ |
| Logic Low Output Voltages | V_{OL} | 0.0 | | | 0.1 | V |
| | | 0.2 | | | 0.4 | V |
| Input Current per Channel | I_i | -10 | +0.01 | +10 | μA | $0\text{ V} \leq V_{Ix} \leq V_{DDx}$ |
| Supply Current per Channel | | | | | | |
| Quiescent Input Supply Current | $I_{DDI(Q)}$ | 0.3 | | | 0.5 | mA |
| Quiescent Output Supply Current | $I_{DDO(Q)}$ | 0.3 | | | 0.5 | mA |
| Dynamic Input Supply Current | $I_{DDI(D)}$ | 0.10 | | | | mA/Mbps |
| Dynamic Output Supply Current | $I_{DDO(D)}$ | 0.03 | | | | mA/Mbps |
| AC SPECIFICATIONS | | | | | | |
| Common-Mode Transient Immunity ¹ | $ CM $ | 25 | 35 | | kV/ μs | $V_{Ix} = V_{DDx}$, $V_{CM} = 1000\text{ V}$, transient magnitude = 800 V |
| Refresh Rate | f_r | 1.1 | | | | Mbps |

¹ $|CM|$ is the maximum common-mode voltage slew rate that can be sustained while maintaining $V_o > 0.8 V_{DD}$. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges.

ELECTRICAL CHARACTERISTICS—MIXED 5 V/3.3 V, 105°C OPERATION

All typical specifications are at $T_A = 25^\circ\text{C}$, $V_{DD1} = 5\text{ V}$, $V_{DD2} = 3.3\text{ V}$. Minimum/maximum specifications apply over the entire recommended operation range: $4.5\text{ V} \leq V_{DD1} \leq 5.5\text{ V}$, $3.0\text{ V} \leq V_{DD2} \leq 3.6\text{ V}$, and $-40^\circ\text{C} \leq T_A \leq +105^\circ\text{C}$, unless otherwise noted. Switching specifications are tested with $C_L = 15\text{ pF}$, and CMOS signal levels, unless otherwise noted.

Table 7.

| Parameter | Symbol | A Grade | | | B Grade | | | C Grade | | | Unit | Test Conditions/Comments |
|--------------------------|--------------------|---------|-----|-----|---------|-----|-----|---------|-----|-----|-------|--------------------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | |
| SWITCHING SPECIFICATIONS | | | | | | | | | | | | |
| Data Rate | | | | 1 | | | 10 | | | 25 | Mbps | Within PWD limit |
| Propagation Delay | t_{PHL}, t_{PLH} | 15 | | 150 | 15 | | 55 | 15 | | 50 | ns | 50% input to 50% output |
| Pulse Width Distortion | PWD | | | 40 | | | 3 | | | 3 | ns | $ t_{PLH} - t_{PHL} $ |
| Change vs. Temperature | | | 6 | | | 5 | | | 5 | | ps/°C | |
| Pulse Width | PW | 1000 | | | 100 | | | 40 | | | ns | Within PWD limit |
| Propagation Delay Skew | t_{PSK} | | | 50 | | | 22 | | | 15 | ns | Between any two units |
| Channel Matching | | | | | | | | | | | | |
| Codirectional | t_{PSKCD} | | | 50 | | | 3 | | | 3 | ns | |
| Opposing-Direction | t_{PSKOD} | | | 50 | | | 22 | | | 15 | ns | |
| Output Rise/Fall Time | t_R/t_F | | 3.0 | | 3.0 | | | | 3.0 | | ns | 10% to 90% |

Table 8.

| Parameter | Symbol | 1 Mbps—A Grade, B Grade, and C Grade | | | 10 Mbps—B Grade and C Grade | | | 25 Mbps—C Grade | | | Unit | Test Conditions/Comments |
|----------------|-----------|--------------------------------------|-----|-----|-----------------------------|-----|-----|-----------------|------|-----|------|--------------------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | |
| SUPPLY CURRENT | | | | | | | | | | | | |
| ADuM3200 | I_{DD1} | 1.3 | 1.8 | | 3.5 | 4.6 | | 7.7 | 10.0 | | mA | No load |
| | I_{DD2} | 0.7 | 1.0 | | 1.3 | 1.7 | | 2.3 | 3.0 | | mA | No load |
| ADuM3201 | I_{DD1} | 1.1 | 1.6 | | 3.1 | 4.2 | | 6.9 | 8.9 | | mA | No load |
| | I_{DD2} | 0.8 | 1.6 | | 1.9 | 2.5 | | 3.7 | 5.1 | | mA | No load |

Table 9. For All Models

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
|---|--------------|-----------------|-----------------|-----|-------------------|---|
| DC SPECIFICATIONS | | | | | | |
| Logic High Input Threshold | V_{IH} | $0.7 V_{DDx}$ | | | V | |
| Logic Low Input Threshold | V_{IL} | | | | $0.3 V_{DDx}$ | V |
| Logic High Output Voltages | V_{OH} | $V_{DDx} - 0.1$ | V_{DDx} | | V | $I_{Ox} = -20\ \mu\text{A}$, $V_{ix} = V_{ixH}$ |
| | | $V_{DDx} - 0.5$ | $V_{DDx} - 0.2$ | | V | $I_{Ox} = -3.2\ \text{mA}$, $V_{ix} = V_{ixH}$ |
| Logic Low Output Voltages | V_{OL} | | 0.0 | 0.1 | V | $I_{Ox} = 20\ \mu\text{A}$, $V_{ix} = V_{ixL}$ |
| | | | 0.2 | 0.4 | V | $I_{Ox} = 3.2\ \text{mA}$, $V_{ix} = V_{ixL}$ |
| Input Current per Channel | I_i | -10 | +0.01 | +10 | μA | $0\text{ V} \leq V_{ix} \leq V_{DDx}$ |
| Supply Current per Channel | | | | | | |
| Quiescent Input Supply Current | $I_{DDI(Q)}$ | | 0.4 | 0.8 | mA | $V_{IA} = V_{IB} = 0\text{ V}$ |
| Quiescent Output Supply Current | $I_{DDO(Q)}$ | | 0.3 | 0.5 | mA | $V_{IA} = V_{IB} = 0\text{ V}$ |
| Dynamic Input Supply Current | $I_{DDI(D)}$ | | 0.19 | | mA/Mbps | |
| Dynamic Output Supply Current | $I_{DDO(D)}$ | | 0.03 | | mA/Mbps | |
| AC SPECIFICATIONS | | | | | | |
| Common-Mode Transient Immunity ¹ | $ CM $ | 25 | 35 | | kV/ μs | $V_{ix} = V_{DDx}$, $V_{CM} = 1000\text{ V}$, transient magnitude = 800 V |
| Refresh Rate | f_r | | 1.2 | | Mbps | |

¹ $|CM|$ is the maximum common-mode voltage slew rate that can be sustained while maintaining $V_o > 0.8 V_{DD}$. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges.

ELECTRICAL CHARACTERISTICS—MIXED 3.3 V/5 V, 105°C OPERATION

All typical specifications are at $T_A = 25^\circ\text{C}$, $V_{DD1} = 3.3\text{ V}$, $V_{DD2} = 5.0\text{ V}$. Minimum/maximum specifications apply over the entire recommended operation range: $3.0\text{ V} \leq V_{DD1} \leq 3.6\text{ V}$, $4.5\text{ V} \leq V_{DD2} \leq 5.5\text{ V}$, and $-40^\circ\text{C} \leq T_A \leq +105^\circ\text{C}$, unless otherwise noted. Switching specifications are tested with $C_L = 15\text{ pF}$ and CMOS signal levels, unless otherwise noted.

Table 10.

| Parameter | Symbol | A Grade | | | B Grade | | | C Grade | | | Unit | Test Conditions/Comments |
|--------------------------|--------------------|---------|-----|-----|---------|-----|-----|---------|-----|-----|-------|--------------------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | |
| SWITCHING SPECIFICATIONS | | | | | | | | | | | | |
| Data Rate | | | | 1 | | 10 | | | 25 | | Mbps | Within PWD limit |
| Propagation Delay | t_{PHL}, t_{PLH} | 15 | | 150 | 15 | | 55 | 15 | | 50 | ns | 50% input to 50% output |
| Pulse Width Distortion | PWD | | | | | | | | | | | |
| ADuM3200 | | | | 40 | | | 3 | | | 3 | ns | $ t_{PLH} - t_{PHL} $ |
| ADuM3201 | | | | 40 | | | 4 | | | 4 | ns | $ t_{PLH} - t_{PHL} $ |
| Change vs. Temperature | | | 6 | | | 5 | | | 5 | | ps/°C | |
| Pulse Width | PW | 1000 | | | 100 | | | 40 | | | ns | Within PWD limit |
| Propagation Delay Skew | t_{PSK} | | | 50 | | | 22 | | | 15 | ns | Between any two units |
| Channel Matching | | | | | | | | | | | | |
| Codirectional | t_{PSKCD} | | | 50 | | | 3 | | | 3 | ns | |
| Opposing-Direction | t_{PSKOD} | | | 50 | | | 22 | | | 15 | ns | |
| Output Rise/Fall Time | t_R/t_F | | 2.5 | | | 2.5 | | | 2.5 | | ns | 10% to 90% |

Table 11.

| Parameter | Symbol | 1 Mbps—A Grade, B Grade, and C Grade | | | 10 Mbps—B Grade and C Grade | | | 25 Mbps—C Grade | | | Unit | Test Conditions/Comments |
|----------------|-----------|--------------------------------------|-----|-----|-----------------------------|-----|-----|-----------------|-----|-----|------|--------------------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | |
| SUPPLY CURRENT | | | | | | | | | | | | |
| ADuM3200 | I_{DD1} | 0.8 | 1.3 | | 2.2 | 3.2 | | 4.8 | 6.4 | | mA | No load |
| | I_{DD2} | 1.0 | 1.6 | | 2.0 | 2.8 | | 3.8 | 4.9 | | mA | No load |
| ADuM3201 | I_{DD1} | 0.7 | 1.3 | | 1.9 | 2.5 | | 4.1 | 5.3 | | mA | No load |
| | I_{DD2} | 1.3 | 1.9 | | 3.1 | 4.0 | | 6.1 | 8.3 | | mA | No load |

Table 12. For All Models

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
|---|--------------|-----------------|-----------------|-----|-------------------|---|
| DC SPECIFICATIONS | | | | | | |
| Logic High Input Threshold | V_{IH} | $0.7 V_{DDx}$ | | | V | |
| Logic Low Input Threshold | V_{IL} | | | | V | |
| Logic High Output Voltages | V_{OH} | $V_{DDx} - 0.1$ | V_{DDx} | | V | $I_{Ox} = -20\text{ }\mu\text{A}$, $V_{Ix} = V_{IxH}$ |
| | | $V_{DDx} - 0.5$ | $V_{DDx} - 0.2$ | | V | $I_{Ox} = -3.2\text{ mA}$, $V_{Ix} = V_{IxH}$ |
| Logic Low Output Voltages | V_{OL} | 0.0 | | | V | $I_{Ox} = 20\text{ }\mu\text{A}$, $V_{Ix} = V_{IxL}$ |
| | | 0.2 | | | V | $I_{Ox} = 3.2\text{ mA}$, $V_{Ix} = V_{IxL}$ |
| | | 0.4 | | | V | |
| Input Current per Channel | I_i | -10 | +0.01 | +10 | μA | $0\text{ V} \leq V_{Ix} \leq V_{DDx}$ |
| Supply Current per Channel | | | | | | |
| Quiescent Input Supply Current | $I_{DDI(Q)}$ | | 0.3 | 0.5 | mA | $V_{IA} = V_{IB} = 0\text{ V}$ |
| Quiescent Output Supply Current | $I_{DDO(Q)}$ | | 0.5 | 0.6 | mA | $V_{IA} = V_{IB} = 0\text{ V}$ |
| Dynamic Input Supply Current | $I_{DDI(D)}$ | | 0.10 | | mA/Mbps | |
| Dynamic Output Supply Current | $I_{DDO(D)}$ | | 0.05 | | mA/Mbps | |
| AC SPECIFICATIONS | | | | | | |
| Common-Mode Transient Immunity ¹ | $ CM $ | 25 | 35 | | kV/ μs | $V_{Ix} = V_{DDx}$, $V_{CM} = 1000\text{ V}$, transient magnitude = 800 V |
| Refresh Rate | f_r | | 1.1 | | Mbps | |

¹ $|CM|$ is the maximum common-mode voltage slew rate that can be sustained while maintaining $V_O > 0.8 V_{DD}$. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges.

ELECTRICAL CHARACTERISTICS—5 V, 125°C OPERATION

All typical specifications are at $T_A = 25^\circ\text{C}$, $V_{DD1} = V_{DD2} = 5\text{ V}$. Minimum/maximum specifications apply over the entire recommended operation range: $4.5\text{ V} \leq V_{DD1} \leq 5.5\text{ V}$, $4.5\text{ V} \leq V_{DD2} \leq 5.5\text{ V}$, and $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$, unless otherwise noted. Switching specifications are tested with $C_L = 15\text{ pF}$ and CMOS signal levels, unless otherwise noted.

Table 13.

| Parameter | Symbol | WA Grade | | | WB Grade | | | WC Grade | | | Unit | Test Conditions/Comments |
|--------------------------|-----------------------|----------|-----|-----|----------|-----|-----|----------|-----|-----|-------|--------------------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | |
| SWITCHING SPECIFICATIONS | | | | | | | | | | | | |
| Data Rate | | | | 1 | | | 10 | | | 25 | Mbps | Within PWD limit |
| Propagation Delay | t_{PHL} , t_{PLH} | 20 | | 150 | 20 | | 50 | 20 | | 45 | ns | 50% input to 50% output |
| Pulse Width Distortion | PWD | | | 40 | | | 3 | | | 3 | ns | $ t_{PLH} - t_{PHL} $ |
| Change vs. Temperature | | | 6 | | | 5 | | 5 | | | ps/°C | |
| Pulse Width | PW | 1000 | | | 100 | | | 40 | | | ns | Within PWD limit |
| Propagation Delay Skew | t_{PSK} | | | 100 | | | 15 | | | 15 | ns | Between any two units |
| Channel Matching | | | | | | | | | | | | |
| Codirectional | t_{PSKCD} | | | 50 | | | 3 | | | 3 | ns | |
| Opposing-Direction | t_{PSKOD} | | | 50 | | | 15 | | | 15 | ns | |
| Output Rise/Fall Time | t_R/t_F | | 2.5 | | 2.5 | | | 2.5 | | | ns | 10% to 90% |

Table 14.

| Parameter | Symbol | 1 Mbps—WA Grade, WB Grade, and WC Grade | | | 10 Mbps—WB Grade and WC Grade | | | 25 Mbps—WC Grade | | | Unit | Test Conditions/ Comments |
|----------------|-----------|---|-----|-----|----------------------------------|-----|-----|---------------------|-----|------|------|------------------------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | |
| SUPPLY CURRENT | | | | | | | | | | | | |
| ADuM3200 | I_{DD1} | | 1.3 | 2.0 | | 3.5 | 4.6 | | 7.7 | 10.0 | mA | No load |
| | I_{DD2} | | 1.0 | 1.6 | | 1.7 | 2.8 | | 3.1 | 3.9 | mA | No load |
| ADuM3201 | I_{DD1} | | 1.1 | 1.5 | | 2.6 | 3.4 | | 5.3 | 6.8 | mA | No load |
| | I_{DD2} | | 1.3 | 1.8 | | 3.1 | 4.0 | | 6.4 | 8.3 | mA | No load |

Table 15. For All Models

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
|---|--------------|-----------------|-----------------|-----|-------------------|--|
| DC SPECIFICATIONS | | | | | | |
| Logic High Input Threshold | V_{IH} | $0.7 V_{DDx}$ | | | V | |
| Logic Low Input Threshold | V_{IL} | | | | V | |
| Logic High Output Voltages | V_{OH} | $V_{DDx} - 0.1$ | V_{DDx} | | V | $I_{Ox} = -20\ \mu\text{A}$, $V_{Ix} = V_{IxH}$ |
| | | $V_{DDx} - 0.5$ | $V_{DDx} - 0.2$ | | V | $I_{Ox} = -3.2\ \text{mA}$, $V_{Ix} = V_{IxH}$ |
| Logic Low Output Voltages | V_{OL} | 0.0 | 0.1 | | V | $I_{Ox} = 20\ \mu\text{A}$, $V_{Ix} = V_{IxL}$ |
| | | | 0.2 | 0.4 | V | $I_{Ox} = 3.2\ \text{mA}$, $V_{Ix} = V_{IxL}$ |
| Input Current per Channel | I_I | -10 | +0.01 | +10 | μA | $0\text{ V} \leq V_{Ix} \leq V_{DDx}$ |
| Supply Current per Channel | | | | | | |
| Quiescent Input Supply Current | $I_{DD(IQ)}$ | | 0.4 | 0.8 | mA | $V_{IA} = V_{IB} = 0\text{ V}$ |
| Quiescent Output Supply Current | $I_{DD(OQ)}$ | | 0.5 | 0.6 | mA | $V_{IA} = V_{IB} = 0\text{ V}$ |
| Dynamic Input Supply Current | $I_{DD(ID)}$ | | 0.19 | | mA/Mbps | |
| Dynamic Output Supply Current | $I_{DD(OD)}$ | | 0.05 | | mA/Mbps | |
| AC SPECIFICATIONS | | | | | | |
| Common-Mode Transient Immunity ¹ | $ CM $ | 25 | 35 | | kV/ μs | $V_{Ix} = V_{DDx}$, $V_{CM} = 1000\text{ V}$, transient magnitude = 800 V |
| Refresh Rate | f_r | | 1.2 | | Mbps | |

¹ $|CM|$ is the maximum common-mode voltage slew rate that can be sustained while maintaining $V_O > 0.8 V_{DD}$. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges.

ELECTRICAL CHARACTERISTICS—3.3 V, 125°C OPERATION

All typical specifications are at $T_A = 25^\circ\text{C}$, $V_{DD1} = V_{DD2} = 3.3\text{ V}$. Minimum/maximum specifications apply over the entire recommended operation range: $3.0\text{ V} \leq V_{DD1} \leq 3.6\text{ V}$, $3.0\text{ V} \leq V_{DD2} \leq 3.6\text{ V}$, and $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$, unless otherwise noted. Switching specifications are tested with $C_L = 15\text{ pF}$ and CMOS signal levels, unless otherwise noted.

Table 16.

| Parameter | Symbol | WA Grade | | | WB Grade | | | WC Grade | | | Unit | Test Conditions/Comments |
|--------------------------|--------------------|----------|-----|-----|----------|-----|-----|----------|-----|-----|-------|--------------------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | |
| SWITCHING SPECIFICATIONS | | | | | | | | | | | | |
| Data Rate | | | | 1 | | | 10 | | | 25 | Mbps | Within PWD limit |
| Propagation Delay | t_{PHL}, t_{PLH} | 20 | | 150 | 20 | | 60 | 20 | | 55 | ns | 50% input to 50% output |
| Pulse Width Distortion | PWD | | | | | | | | | | | |
| ADuM3200 | | | | 40 | | | 3 | | | 3 | ns | $ t_{PLH} - t_{PHL} $ |
| ADuM3201 | | | | 40 | | | 4 | | | 4 | ns | $ t_{PLH} - t_{PHL} $ |
| Change vs. Temperature | | | 6 | | | 5 | | | 5 | | ps/°C | |
| Pulse Width | PW | 1000 | | | 100 | | | 40 | | | ns | Within PWD limit |
| Propagation Delay Skew | t_{PSK} | | | 100 | | | 22 | | | 16 | ns | Between any two units |
| Channel Matching | | | | | | | | | | | | |
| Codirectional | t_{PSKCD} | | | 50 | | | 3 | | | 3 | ns | |
| Opposing-Direction | t_{PSKOD} | | | 50 | | | 22 | | | 16 | ns | |
| Output Rise/Fall Time | t_R/t_F | | 3.0 | | | 3.0 | | | 3.0 | | ns | 10% to 90% |

Table 17.

| Parameter | Symbol | 1 Mbps—WA Grade, WB Grade, and WC Grade | | | 10 Mbps—WB Grade and WC Grade | | | 25 Mbps—WC Grade | | | Unit | Test Conditions/Comments | |
|----------------|-----------|---|-----|-----|-------------------------------|-----|-----|------------------|-----|-----|------|--------------------------|---------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | | |
| SUPPLY CURRENT | | | | | | | | | | | | | |
| ADuM3200 | I_{DD1} | 0.8 | | 1.3 | | | 2.0 | 3.2 | | 4.3 | 6.4 | mA | No load |
| | I_{DD2} | 0.7 | | 1.0 | | | 1.1 | 1.7 | | 1.8 | 2.4 | mA | No load |
| ADuM3201 | I_{DD1} | 0.7 | | 1.3 | | | 1.5 | 2.1 | | 3.0 | 4.2 | mA | No load |
| | I_{DD2} | 0.8 | | 1.6 | | | 1.9 | 2.4 | | 3.6 | 5.1 | mA | No load |

Table 18. For All Models

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
|---|--------------|-----------------|-----------------|-----|-------------------|--|
| DC SPECIFICATIONS | | | | | | |
| Logic High Input Threshold | V_{IH} | $0.7 V_{DDx}$ | | | V | |
| Logic Low Input Threshold | V_{IL} | | | | $0.3 V_{DDx}$ | V |
| Logic High Output Voltages | V_{OH} | $V_{DDx} - 0.1$ | V_{DDx} | | V | $I_{Ox} = -20\ \mu\text{A}, V_{Ix} = V_{IxH}$ |
| | | $V_{DDx} - 0.5$ | $V_{DDx} - 0.2$ | | V | $I_{Ox} = -3.2\ \text{mA}, V_{Ix} = V_{IxH}$ |
| Logic Low Output Voltages | V_{OL} | 0.0 | | 0.1 | V | $I_{Ox} = 20\ \mu\text{A}, V_{Ix} = V_{IxL}$ |
| | | 0.2 | | 0.4 | V | $I_{Ox} = 3.2\ \text{mA}, V_{Ix} = V_{IxL}$ |
| Input Current per Channel | I_i | -10 | +0.01 | +10 | μA | $0\text{ V} \leq V_{Ix} \leq V_{DDx}$ |
| Supply Current per Channel | | | | | | |
| Quiescent Input Supply Current | $I_{DDI(Q)}$ | | 0.3 | 0.5 | mA | $V_{IA} = V_{IB} = 0\text{ V}$ |
| Quiescent Output Supply Current | $I_{DDO(Q)}$ | | 0.3 | 0.5 | mA | $V_{IA} = V_{IB} = 0\text{ V}$ |
| Dynamic Input Supply Current | $I_{DDI(D)}$ | | 0.10 | | mA/Mbps | |
| Dynamic Output Supply Current | $I_{DDO(D)}$ | | 0.03 | | mA/Mbps | |
| AC SPECIFICATIONS | | | | | | |
| Common-Mode Transient Immunity ¹ | $ CM $ | 25 | 35 | | kV/ μs | $V_{Ix} = V_{DDx}, V_{CM} = 1000\text{ V}$, transient magnitude = 800 V |
| Refresh Rate | f_r | | 1.1 | | Mbps | |

¹ $|CM|$ is the maximum common-mode voltage slew rate that can be sustained while maintaining $V_O > 0.8 V_{DD}$. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges.

ELECTRICAL CHARACTERISTICS—MIXED 5 V/3.3 V, 125°C OPERATION

All typical specifications are at $T_A = 25^\circ\text{C}$, $V_{DD1} = 5\text{ V}$, $V_{DD2} = 3.3\text{ V}$. Minimum/maximum specifications apply over the entire recommended operation range: $4.5\text{ V} \leq V_{DD1} \leq 5.5\text{ V}$, $3.0\text{ V} \leq V_{DD2} \leq 3.6\text{ V}$, and $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$, unless otherwise noted. Switching specifications are tested with $C_L = 15\text{ pF}$ and CMOS signal levels, unless otherwise noted.

Table 19.

| Parameter | Symbol | WA Grade | | | WB Grade | | | WC Grade | | | Unit | Test Conditions/Comments |
|--------------------------|--------------------|----------|-----|-----|----------|-----|-----|----------|-----|-----|-------|--------------------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | |
| SWITCHING SPECIFICATIONS | | | | | | | | | | | | |
| Data Rate | | | | 1 | | | 10 | | | 25 | Mbps | Within PWD limit |
| Propagation Delay | t_{PHL}, t_{PLH} | 15 | | 150 | 15 | | 55 | 15 | | 50 | ns | 50% input to 50% output |
| Pulse Width Distortion | PWD | | | 40 | | | 3 | | | 3 | ns | $ t_{PLH} - t_{PHL} $ |
| Change vs. Temperature | | | 6 | | | 5 | | 5 | | | ps/°C | |
| Pulse Width | PW | 1000 | | | 100 | | | 40 | | | ns | Within PWD limit |
| Propagation Delay Skew | t_{PSK} | | | 50 | | | 22 | | | 15 | ns | Between any two units |
| Channel Matching | | | | | | | | | | | | |
| Codirectional | t_{PSKCD} | | | 50 | | | 3 | | | 3 | ns | |
| Opposing-Direction | t_{PSKOD} | | | 50 | | | 22 | | | 15 | ns | |
| Output Rise/Fall Time | t_R/t_F | | 3.0 | | 3.0 | | | 3.0 | | | ns | 10% to 90% |

Table 20.

| Parameter | Symbol | 1 Mbps—WA Grade, WB Grade, and WC Grade | | | 10 Mbps—WB Grade and WC Grade | | | 25 Mbps—WC Grade | | | Unit | Test Conditions/Comments |
|----------------|-----------|---|-----|-----|-------------------------------|-----|-----|------------------|-----|------|------|--------------------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | |
| SUPPLY CURRENT | | | | | | | | | | | | |
| ADuM3200 | I_{DD1} | | 1.3 | 2.0 | | 3.5 | 4.6 | | 7.7 | 10.0 | mA | No load |
| | I_{DD2} | | 0.7 | 1.0 | | 1.1 | 1.7 | | 1.8 | 2.4 | mA | No load |
| ADuM3201 | I_{DD1} | | 1.1 | 1.5 | | 2.6 | 3.4 | | 5.3 | 6.8 | mA | No load |
| | I_{DD2} | | 0.8 | 1.6 | | 1.9 | 2.4 | | 3.6 | 5.1 | mA | No load |

Table 21. For All Models

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
|---|--------------|-----------------|-----------------|-----|-------------------|---|
| DC SPECIFICATIONS | | | | | | |
| Logic High Input Threshold | V_{IH} | $0.7 V_{DDx}$ | | | V | |
| Logic Low Input Threshold | V_{IL} | | | | V | |
| Logic High Output Voltages | V_{OH} | $V_{DDx} - 0.1$ | V_{DDx} | | V | $I_{Ox} = -20\text{ }\mu\text{A}$, $V_{Ix} = V_{IxH}$ |
| | | $V_{DDx} - 0.5$ | $V_{DDx} - 0.2$ | | V | $I_{Ox} = -3.2\text{ mA}$, $V_{Ix} = V_{IxH}$ |
| Logic Low Output Voltages | V_{OL} | | 0.0 | 0.1 | V | $I_{Ox} = 20\text{ }\mu\text{A}$, $V_{Ix} = V_{IxL}$ |
| | | | 0.2 | 0.4 | V | $I_{Ox} = 3.2\text{ mA}$, $V_{Ix} = V_{IxL}$ |
| Input Current per Channel | I_i | -10 | +0.01 | +10 | μA | $0\text{ V} \leq V_{Ix} \leq V_{DDx}$ |
| Supply Current per Channel | | | | | | |
| Quiescent Input Supply Current | $I_{DDI(Q)}$ | | 0.4 | 0.8 | mA | $V_{IA} = V_{IB} = 0\text{ V}$ |
| Quiescent Output Supply Current | $I_{DDO(Q)}$ | | 0.3 | 0.5 | mA | $V_{IA} = V_{IB} = 0\text{ V}$ |
| Dynamic Input Supply Current | $I_{DDI(D)}$ | | 0.19 | | mA/Mbps | |
| Dynamic Output Supply Current | $I_{DDO(D)}$ | | 0.03 | | mA/Mbps | |
| AC SPECIFICATIONS | | | | | | |
| Common-Mode Transient Immunity ¹ | $ CM $ | 25 | 35 | | kV/ μs | $V_{Ix} = V_{DDx}$, $V_{CM} = 1000\text{ V}$, transient magnitude = 800 V |
| Refresh Rate | f_r | | 1.2 | | Mbps | |

¹ $|CM|$ is the maximum common-mode voltage slew rate that can be sustained while maintaining $V_O > 0.8 V_{DD}$. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges.

ELECTRICAL CHARACTERISTICS—MIXED 3.3 V/5 V, 125°C OPERATION

All typical specifications are at $T_A = 25^\circ\text{C}$, $V_{DD1} = 3.3\text{ V}$, $V_{DD2} = 5.0\text{ V}$. Minimum/maximum specifications apply over the entire recommended operation range: $3.0\text{ V} \leq V_{DD1} \leq 3.6\text{ V}$, $4.5\text{ V} \leq V_{DD2} \leq 5.5\text{ V}$, and $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$, unless otherwise noted. Switching specifications are tested with $C_L = 15\text{ pF}$ and CMOS signal levels, unless otherwise noted.

Table 22.

| Parameter | Symbol | WA Grade | | | WB Grade | | | WC Grade | | | Unit | Test Conditions/Comments |
|--------------------------|--------------------|----------|-----|-----|----------|-----|-----|----------|-----|-----|-------|--------------------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | |
| SWITCHING SPECIFICATIONS | | | | | | | | | | | | |
| Data Rate | | | | 1 | | | 10 | | | 25 | Mbps | Within PWD limit |
| Propagation Delay | t_{PHL}, t_{PLH} | 15 | | 150 | 15 | | 55 | 15 | | 50 | ns | 50% input to 50% output |
| Pulse Width Distortion | PWD | | | | | | | | | | | |
| ADuM3200 | | | | 40 | | | 3 | | | 3 | ns | $ t_{PLH} - t_{PHL} $ |
| ADuM3201 | | | | 40 | | | 4 | | | 4 | ns | $ t_{PLH} - t_{PHL} $ |
| Change vs. Temperature | | | 6 | | | 5 | | | 5 | | ps/°C | |
| Pulse Width | PW | 1000 | | | 100 | | | 40 | | | ns | Within PWD limit |
| Propagation Delay Skew | t_{PSK} | | | 50 | | | 22 | | | 15 | ns | Between any two units |
| Channel Matching | | | | | | | | | | | | |
| Codirectional | t_{PSKCD} | | | 50 | | | 3 | | | 3 | ns | |
| Opposing-Direction | t_{PSKOD} | | | 50 | | | 22 | | | 15 | ns | |
| Output Rise/Fall Time | t_R/t_F | | 2.5 | | | 2.5 | | | 2.5 | | ns | 10% to 90% |

Table 23.

| Parameter | Symbol | 1 Mbps—WA Grade, WB Grade, and WC Grade | | | 10 Mbps—WB Grade and WC Grade | | | 25 Mbps—WC Grade | | | Unit | Test Conditions/Comments | |
|----------------|-----------|---|-----|-----|-------------------------------|-----|-----|------------------|-----|-----|------|--------------------------|---------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | | |
| SUPPLY CURRENT | | | | | | | | | | | | | |
| ADuM3200 | I_{DD1} | 0.8 | | 1.3 | | | 2.0 | 3.2 | | 4.3 | 6.4 | mA | No load |
| | I_{DD2} | 1.0 | | 1.6 | | | 1.7 | 2.8 | | 3.1 | 3.9 | mA | No load |
| ADuM3201 | I_{DD1} | 0.7 | | 1.3 | | | 1.5 | 2.1 | | 3.0 | 4.2 | mA | No load |
| | I_{DD2} | 1.3 | | 1.8 | | | 3.1 | 4.0 | | 6.4 | 8.3 | mA | No load |

Table 24. For All Models

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
|---|--------------|-----------------|-----------------|-----|-------------------|---|
| DC SPECIFICATIONS | | | | | | |
| Logic High Input Threshold | V_{IH} | $0.7 V_{DDX}$ | | | V | |
| Logic Low Input Threshold | V_{IL} | | | | $0.3 V_{DDX}$ | V |
| Logic High Output Voltages | V_{OH} | $V_{DDX} - 0.1$ | V_{DDX} | | V | $I_{OX} = -20\ \mu\text{A}$, $V_{IX} = V_{IXH}$ |
| | | $V_{DDX} - 0.5$ | $V_{DDX} - 0.2$ | | V | $I_{OX} = -3.2\ \text{mA}$, $V_{IX} = V_{IXH}$ |
| Logic Low Output Voltages | V_{OL} | | 0.0 | 0.1 | V | $I_{OX} = 20\ \mu\text{A}$, $V_{IX} = V_{IXL}$ |
| | | | 0.2 | 0.4 | V | $I_{OX} = 3.2\ \text{mA}$, $V_{IX} = V_{IXL}$ |
| Input Current per Channel | I_i | -10 | +0.01 | +10 | μA | $0\text{ V} \leq V_{IX} \leq V_{DDX}$ |
| Supply Current per Channel | | | | | | |
| Quiescent Input Supply Current | $I_{DDI(Q)}$ | | 0.3 | 0.5 | mA | $V_{IA} = V_{IB} = 0\text{ V}$ |
| Quiescent Output Supply Current | $I_{DDO(Q)}$ | | 0.5 | 0.6 | mA | $V_{IA} = V_{IB} = 0\text{ V}$ |
| Dynamic Input Supply Current | $I_{DDI(D)}$ | | 0.10 | | mA/Mbps | |
| Dynamic Output Supply Current | $I_{DDO(D)}$ | | 0.05 | | mA/Mbps | |
| AC SPECIFICATIONS | | | | | | |
| Common-Mode Transient Immunity ¹ | $ CM $ | 25 | 35 | | kV/ μs | $V_{IX} = V_{DDX}$, $V_{CM} = 1000\text{ V}$, transient magnitude = 800 V |
| Refresh Rate | f_r | | 1.1 | | Mbps | |

¹ $|CM|$ is the maximum common-mode voltage slew rate that can be sustained while maintaining $V_O > 0.8 V_{DD}$. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges.

PACKAGE CHARACTERISTICS

Table 25.

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
|--|------------------|-----|------------------|-----|------|---|
| Resistance (Input to Output) ¹ | R _{I-O} | | 10 ¹² | | Ω | |
| Capacitance (Input to Output) ¹ | C _{I-O} | | 1.0 | | pF | f = 1 MHz |
| Input Capacitance | C _I | | 4.0 | | pF | |
| IC Junction-to-Case Thermal Resistance, Side 1 | θ _{JCI} | | 46 | | °C/W | Thermocouple located at center of package underside |
| IC Junction-to-Case Thermal Resistance, Side 2 | θ _{JCO} | | 41 | | °C/W | |

¹ The device is considered a 2-terminal device; Pin 1, Pin 2, Pin 3, and Pin 4 are shorted together, and Pin 5, Pin 6, Pin 7, and Pin 8 are shorted together.

REGULATORY INFORMATION

The ADuM3200/ADuM3201 devices are approved by the organizations listed in Table 26. Refer to Table 31 and the Insulation Lifetime section for details regarding recommended maximum working voltages for specific cross-isolation waveforms and insulation levels.

Table 26.

| UL | CSA | CQC | VDE |
|---|--|--|--|
| Recognized Under UL 1577 Component Recognition Program ¹ | Approved under CSA Component Acceptance Notice 5A | Approved under CQC11-471543-2012 | Certified according to DIN V VDE V 0884-10 (VDE V 0884-10): 2006-12 ² |
| Single/Basic 2500 V rms Isolation Voltage | Basic insulation per CSA 60950-1-03 and IEC 60950-1, 400 V rms (566 V peak) maximum working voltage, functional insulation per CSA 60950-1-03 and IEC 60950-1, 800 V rms (1131 V peak) maximum working voltage | Basic insulation per GB4943.1-2011, 400 V rms (588 V peak) maximum working voltage, tropical climate, altitude ≤ 5000 meters | Reinforced insulation, 560 V peak |
| File E214100 | File 205078 | File CQC14001117250 | File 2471900-4880-0001 |

¹ In accordance with UL 1577, each ADuM3200/ADuM3201 is proof-tested by applying an insulation test voltage ≥ 3000 V rms for 1 second (current leakage detection limit = 5 μA).

² In accordance with DIN V VDE V 0884-10, each ADuM3200/ADuM3201 is proof-tested by applying an insulation test voltage ≥ 1050 V peak for 1 second (partial discharge detection limit = 5 pC). An asterisk (*) marking branded on the component designates DIN V VDE V 0884-10 approval.

INSULATION AND SAFETY-RELATED SPECIFICATIONS

Table 27.

| Parameter | Symbol | Value | Unit | Test Conditions/Comments |
|--|--------|-----------|-------|--|
| Rated Dielectric Insulation Voltage | | 2500 | V rms | 1-minute duration |
| Minimum External Air Gap (Clearance) | L(I01) | 4.90 min | mm | Measured from input terminals to output terminals, shortest distance through air |
| Minimum External Tracking (Creepage) | L(I02) | 4.01 min | mm | Measured from input terminals to output terminals, shortest distance path along body |
| Minimum Internal Gap (Internal Clearance) | | 0.017 min | mm | Insulation distance through insulation |
| Tracking Resistance (Comparative Tracking Index) | CTI | >400 | V | DIN IEC 112/VDE 0303 Part 1 |
| Isolation Group | | II | | Material Group (DIN VDE 0110, 1/89, Table 1) |

DIN V VDE V 0884-10 (VDE V 0884-10) INSULATION CHARACTERISTICS

These isolators are suitable for reinforced isolation only within the safety limit data. Maintenance of the safety data is ensured by protective circuits. The asterisk (*) marking on the package denotes DIN V VDE V 0884-10 approval for a 560 V peak working voltage.

Table 28.

| Description | Test Conditions/Comments | Symbol | Characteristic | Unit |
|---|--|-------------------|--------------------------------|--------|
| Installation Classification per DIN VDE 0110 For Rated Mains Voltage ≤ 150 V rms For Rated Mains Voltage ≤ 300 V rms For Rated Mains Voltage ≤ 400 V rms | | | I to IV I to III I to II | |
| Climatic Classification | | | 40/105/21 | |
| Pollution Degree per DIN VDE 0110, Table 1 | | | 2 | |
| Maximum Working Insulation Voltage | | V _{IORM} | 560 | V peak |
| Input-to-Output Test Voltage, Method B1 | V _{IORM} × 1.875 = V _{PR} , 100% production test, t _m = 1 sec, partial discharge < 5 pC | V _{PR} | 1050 | V peak |
| Input-to-Output Test Voltage, Method A | V _{IORM} × 1.6 = V _{PR} , t _m = 60 sec, partial discharge < 5 pC | V _{PR} | | |
| After Environmental Tests Subgroup 1 | | | 896 | V peak |
| After Input and/or Safety Test Subgroup 2 and Subgroup 3 | V _{IORM} × 1.2 = V _{PR} , t _m = 60 sec, partial discharge < 5 pC | | 672 | V peak |
| Highest Allowable Overvoltage | Transient overvoltage, t _{TR} = 10 seconds | V _{TR} | 4000 | V peak |
| Safety-Limiting Values | Maximum value allowed in the event of a failure (see Figure 3) | | | |
| Case Temperature | | T _S | 150 | °C |
| Side 1 Current | | I _{S1} | 160 | mA |
| Side 2 Current | | I _{S2} | 170 | mA |
| Insulation Resistance at T _S | V _{IO} = 500 V | R _S | >10 ⁹ | Ω |



Figure 3. Thermal Derating Curve, Dependence of Safety-Limiting Values on Case Temperature, per DIN V VDE V 0884-10

RECOMMENDED OPERATING CONDITIONS

Table 29.

| Parameter | Symbol | Min | Max | Unit |
|--|-------------------------------------|-----|------|------|
| Operating Temperature | T _A | -40 | +105 | °C |
| ADuM3200A/ADuM3201A | | -40 | +105 | °C |
| ADuM3200B/ADuM3201B | | -40 | +105 | °C |
| ADuM3200C/ADuM3201C | | -40 | +105 | °C |
| ADuM3200WA/ADuM3201WA | | -40 | +125 | °C |
| ADuM3200WB/ADuM3201WB | | -40 | +125 | °C |
| ADuM3200WC/ADuM3201WC | | -40 | +125 | °C |
| Supply Voltages ¹ | V _{DD1} , V _{DD2} | 3.0 | 5.5 | V |
| ADuM3200A/ADuM3201A | | 3.0 | 5.5 | V |
| ADuM3200B/ADuM3201B | | 3.0 | 5.5 | V |
| ADuM3200C/ADuM3201C | | 3.0 | 5.5 | V |
| ADuM3200WA/ADuM3201WA | | 3.0 | 5.5 | V |
| ADuM3200WB/ADuM3201WB | | 3.0 | 5.5 | V |
| ADuM3200WC/ADuM3201WC | | 3.0 | 5.5 | V |
| Maximum Input Signal Rise and Fall Times | | | 1.0 | ms |

¹ All voltages are relative to their respective ground. See the DC Correctness and Magnetic Field Immunity section for information on immunity to external magnetic fields.

ABSOLUTE MAXIMUM RATINGS

Ambient temperature = 25°C, unless otherwise noted.

Table 30.

| Parameter | Rating |
|---|--------------------------------------|
| Storage Temperature (T_{ST}) | -55°C to +150°C |
| Ambient Operating Temperature (T_A) | -40°C to +125°C |
| Supply Voltages (V_{DD1} , V_{DD2}) ¹ | -0.5 V to +7.0 V |
| Input Voltage (V_{IA} , V_{IB}) ^{1,2} | -0.5 V to $V_{DD1} + 0.5$ V |
| Output Voltage (V_{OA} , V_{OB}) ^{1,2} | -0.5 V to $V_{DDO} + 0.5$ V |
| Average Output Current, per Pin (I_O) ³ | -22 mA to +22 mA |
| Common-Mode Transients (CM_L , CM_H) ⁴ | -100 kV/ μ s to +100 kV/ μ s |

¹ All voltages are relative to their respective ground.

² V_{DD1} and V_{DDO} refer to the supply voltages on the input and output sides of a given channel, respectively.

³ See Figure 3 for maximum rated current values for various temperatures.

⁴ Refers to common-mode transients across the insulation barrier. Common-mode transients exceeding the Absolute Maximum Ratings can cause latch-up or permanent damage.

Table 31. Maximum Continuous Working Voltage¹

| Parameter | Max | Unit | Constraint |
|-------------------------------|------|--------|--|
| AC Voltage, Bipolar Waveform | 565 | V peak | 50-year minimum lifetime |
| AC Voltage, Unipolar Waveform | | | |
| Functional Insulation | 1131 | V peak | Maximum approved working voltage per IEC 60950-1 |
| Basic Insulation | 560 | V peak | Maximum approved working voltage per IEC 60950-1 and VDE V 0884-10 |
| DC Voltage | | | |
| Functional Insulation | 1131 | V peak | Maximum approved working voltage per IEC 60950-1 |
| Basic Insulation | 560 | V peak | Maximum approved working voltage per IEC 60950-1 and VDE V 0884-10 |

¹ Refers to continuous voltage magnitude imposed across the isolation barrier. See the Insulation Lifetime section for more details.

Table 32. ADuM3200 Truth Table (Positive Logic)

| V_{IA} Input | V_{IB} Input | V_{DD1} State | V_{DD2} State | V_{OA} Output | V_{OB} Output | Notes |
|----------------|----------------|-----------------|-----------------|-----------------|-----------------|--|
| H | H | Powered | Powered | H | H | |
| L | L | Powered | Powered | L | L | |
| H | L | Powered | Powered | H | L | |
| L | H | Powered | Powered | L | H | |
| X | X | Unpowered | Powered | H | H | Outputs return to the input state within 1 μ s of V_{DD1} power restoration. |
| X | X | Powered | Unpowered | Indeterminate | Indeterminate | Outputs return to the input state within 1 μ s of V_{DDO} power restoration. |

Table 33. ADuM3201 Truth Table (Positive Logic)

| V_{IA} Input | V_{IB} Input | V_{DD1} State | V_{DD2} State | V_{OA} Output | V_{OB} Output | Notes |
|----------------|----------------|-----------------|-----------------|-----------------|-----------------|--|
| H | H | Powered | Powered | H | H | |
| L | L | Powered | Powered | L | L | |
| H | L | Powered | Powered | H | L | |
| L | H | Powered | Powered | L | H | |
| X | X | Unpowered | Powered | Indeterminate | H | Outputs return to the input state within 1 μ s of V_{DD1} power restoration. |
| X | X | Powered | Unpowered | H | Indeterminate | Outputs return to the input state within 1 μ s of V_{DDO} power restoration. |

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

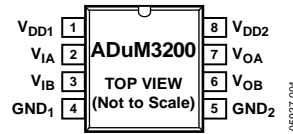


Figure 4. ADuM3200 Pin Configuration

Table 34. ADuM3200 Pin Function Descriptions

| Pin No. | Mnemonic | Description |
|---------|------------------|---|
| 1 | V _{DD1} | Supply Voltage for Isolator Side 1. |
| 2 | V _{IA} | Logic Input A. |
| 3 | V _{IB} | Logic Input B. |
| 4 | GND ₁ | Ground 1. Ground reference for Isolator Side 1. |
| 5 | GND ₂ | Ground 2. Ground reference for Isolator Side 2. |
| 6 | V _{OB} | Logic Output B. |
| 7 | V _{OA} | Logic Output A. |
| 8 | V _{DD2} | Supply Voltage for Isolator Side 2. |



Figure 5. ADuM3201 Pin Configuration

Table 35. ADuM3201 Pin Function Descriptions

| Pin No. | Mnemonic | Description |
|---------|------------------|---|
| 1 | V _{DD1} | Supply Voltage for Isolator Side 1. |
| 2 | V _{OA} | Logic Output A. |
| 3 | V _{IB} | Logic Input B. |
| 4 | GND ₁ | Ground 1. Ground reference for Isolator Side 1. |
| 5 | GND ₂ | Ground 2. Ground reference for Isolator Side 2. |
| 6 | V _{OB} | Logic Output B. |
| 7 | V _{IA} | Logic Input A. |
| 8 | V _{DD2} | Supply Voltage for Isolator Side 2. |

TYPICAL PERFORMANCE CHARACTERISTICS



Figure 6. Typical Input Supply Current per Channel vs. Data Rate for 5 V and 3 V Operation



Figure 9. Typical ADuM3200 I_{DD1} Supply Current vs. Data Rate for 5 V and 3 V Operation



Figure 7. Typical Output Supply Current per Channel vs. Data Rate for 5 V and 3 V Operation (No Output Load)



Figure 10. Typical ADuM3200 I_{DD2} Supply Current vs. Data Rate for 5 V and 3 V Operation



Figure 8. Typical Output Supply Current per Channel vs. Data Rate for 5 V and 3 V Operation (15 pF Output Load)



Figure 11. Typical ADuM3201 I_{DD1} or I_{DD2} Supply Current vs. Data Rate for 5 V and 3 V Operation

APPLICATION INFORMATION

PC BOARD LAYOUT

The ADuM3200/ADuM3201 digital isolators require no external interface circuitry for the logic interfaces. Power supply bypassing is strongly recommended at the input and output supply pins. The capacitor value must be between 0.01 μF and 0.1 μF . The total lead length between both ends of the capacitor and the input power supply pin must not exceed 20 mm. See the [AN-1109 Application Note](#) for board layout guidelines.

SYSTEM-LEVEL ESD CONSIDERATIONS AND ENHANCEMENTS

System-level ESD reliability (for example, per IEC 61000-4-x) is highly dependent on system design which varies widely by application. The ADuM3200/ADuM3201 incorporate many enhancements to make ESD reliability less dependent on system design. The enhancements include:

- ESD protection cells added to all input/output interfaces.
- Key metal trace resistances reduced using wider geometry and paralleling of lines with vias.
- The SCR effect inherent in CMOS devices minimized by use of guarding and isolation technique between PMOS and NMOS devices.
- Areas of high electric field concentration eliminated using 45° corners on metal traces.
- Supply pin overvoltage prevented with larger ESD clamps between each supply pin and the respective ground.

While the ADuM3200/ADuM3201 improve system-level ESD reliability, they are no substitute for a robust system-level design. See the [AN-793 Application Notes](#), *ESD/Latch-Up Considerations with iCoupler Isolation Product*, for detailed recommendations on board layout and system-level design.

PROPAGATION DELAY-RELATED PARAMETERS

Propagation delay is a parameter that describes the time it takes a logic signal to propagate through a component. The propagation delay to a logic low output can differ from the propagation delay to a logic high.



Figure 12. Propagation Delay Parameters

Pulse width distortion is the maximum difference between these two propagation delay values and is an indication of how accurately the input signal timing is preserved.

Channel-to-channel matching refers to the maximum amount that the propagation delay differs between channels within a single ADuM3200/ADuM3201 component.

Propagation delay skew refers to the maximum amount that the propagation delay differs between multiple ADuM3200/ADuM3201 components operating under the same conditions.

DC CORRECTNESS AND MAGNETIC FIELD IMMUNITY

Positive and negative logic transitions at the isolator input cause narrow (~ 1 ns) pulses to be sent to the decoder via the transformer. The decoder is bistable and is therefore either set or reset by the pulses, indicating input logic transitions. In the absence of logic transitions of more than ~ 1 μs at the input, a periodic set of refresh pulses indicative of the correct input state are sent to ensure dc correctness at the output. If the decoder receives no internal pulses for more than about 5 μs , the input side is assumed to be unpowered or nonfunctional, in which case, the isolator output is forced to a default state (see Table 32 and Table 33) by the watchdog timer circuit.

The ADuM3200/ADuM3201 are extremely immune to external magnetic fields. The limitation on the ADuM3200/ADuM3201 magnetic field immunity is set by the condition in which induced voltage in the transformer receiving coil is sufficiently large to either falsely set or reset the decoder. The following analysis defines the conditions under which this can occur. The 3 V operating condition of the ADuM3200/ADuM3201 is examined because it represents the most susceptible mode of operation.

The pulses at the transformer output have an amplitude greater than 1.0 V. The decoder has a sensing threshold at about 0.5 V, therefore establishing a 0.5 V margin in which induced voltages can be tolerated. The voltage induced across the receiving coil is given by

$$V = (-d\beta/dt) \sum \pi r_n^2, n = 1, 2, \dots, N$$

where:

β is the magnetic flux density (gauss).

N is the number of turns in the receiving coil.

r_n is the radius of the n th turn in the receiving coil (cm).

Given the geometry of the receiving coil in the [ADuM3200/ADuM3201](#) and an imposed requirement that the induced voltage is at most 50% of the 0.5 V margin at the decoder, a maximum allowable magnetic field is calculated, as shown in Figure 13.



Figure 13. Maximum Allowable External Magnetic Flux Density

For example, at a magnetic field frequency of 1 MHz, the maximum allowable magnetic field of 0.2 kgauss induces a voltage of 0.25 V at the receiving coil. This is about 50% of the sensing threshold and does not cause a faulty output transition. Similarly, if such an event occurs during a transmitted pulse (and had the worst-case polarity), it reduces the received pulse from >1.0 V to 0.75 V—still well above the 0.5 V sensing threshold of the decoder.

The preceding magnetic flux density values correspond to specific current magnitudes at given distances away from the [ADuM3200/ADuM3201](#) transformers. Figure 14 expresses these allowable current magnitudes as a function of frequency for selected distances. As seen, the [ADuM3200/ADuM3201](#) are extremely immune and can be affected only by extremely large currents operated at high frequency and very close to the component. For the 1 MHz example, one must place a 0.5 kA current 5 mm away from the [ADuM3200/ADuM3201](#) to affect the component operation.

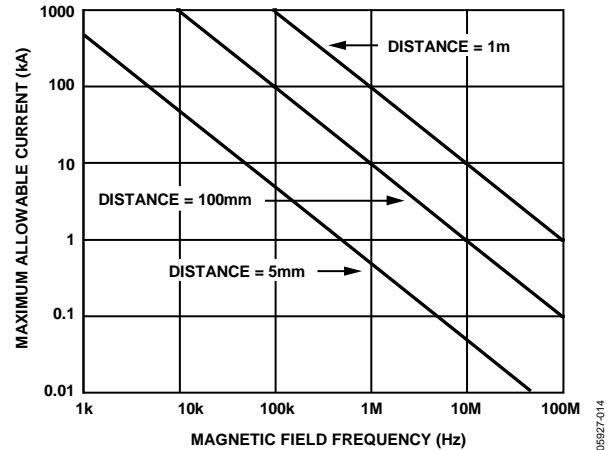


Figure 14. Maximum Allowable Current for Various Current-to-ADuM3200/ADuM3201 Spacings

Note that at combinations of strong magnetic fields and high frequencies, any loops formed by printed circuit board traces could induce sufficiently large error voltages to trigger the threshold of succeeding circuitry. Care must be taken in the layout of such traces to avoid this possibility.

POWER CONSUMPTION

The supply current at a given channel of the [ADuM3200/ADuM3201](#) isolator is a function of the supply voltage, the channel data rate, and the channel output load.

For each input channel, the supply current is given by

$$I_{DDI} = I_{DDI(Q)} \quad f \leq 0.5f_r$$

$$I_{DDI} = I_{DDI(D)} \times (2f - f_r) + I_{DDI(Q)} \quad f > 0.5f_r$$

For each output channel, the supply current is given by

$$I_{DDO} = I_{DDO(Q)} \quad f \leq 0.5f_r$$

$$I_{DDO} = (I_{DDO(D)} + (0.5 \times 10^{-3}) \times C_L V_{DDO}) \times (2f - f_r) + I_{DDO(Q)} \quad f > 0.5f_r$$

where:

$I_{DDI(D)}$, $I_{DDO(D)}$ are the input and output dynamic supply currents per channel (mA/Mbps).

C_L is the output load capacitance (pF).

V_{DDO} is the output supply voltage (V).

f is the input logic signal frequency (MHz, half of the input data rate, NRZ signaling).

f_r is the input stage refresh rate (Mbps).

$I_{DDI(Q)}$, $I_{DDO(Q)}$ are the specified input and output quiescent supply currents (mA).

To calculate the total I_{DD1} and I_{DD2} supply current, the supply currents for each input and output channel corresponding to I_{DD1} and I_{DD2} are calculated and totaled. Figure 6 provides per-channel input supply currents as a function of data rate.

Figure 7 and Figure 8 provide per-channel output supply currents as a function of data rate for an unloaded output condition and for a 15 pF output condition, respectively.

Figure 9 through Figure 11 provide total I_{DD1} and I_{DD2} supply current as a function of data rate for [ADuM3200](#) and [ADuM3201](#) channel configurations.

INSULATION LIFETIME

All insulation structures eventually break down when subjected to voltage stress over a sufficiently long period. The rate of insulation degradation depends upon the characteristics of the voltage waveform applied across the insulation. In addition to the testing performed by the regulatory agencies, Analog Devices carries out an extensive set of evaluations to determine the lifetime of the insulation structure within the [ADuM3200/ADuM3201](#).

Analog Devices performs accelerated life testing using voltage levels higher than the rated continuous working voltage. Acceleration factors for several operating conditions are determined. These factors allow calculation of the time to failure at the actual working voltage.

The values shown in Table 31 summarize the peak voltage for 50 years of service life for a bipolar ac operating condition, and the maximum CSA/VDE approved working voltages. In many cases, the approved working voltage is higher than the 50-year service life voltage. Operation at these high working voltages can lead to shortened insulation life.

The insulation lifetime of the [ADuM3200/ADuM3201](#) depends on the voltage waveform type imposed across the isolation barrier. The *iCoupler* insulation structure degrades at different rates depending on whether the waveform is bipolar ac, unipolar ac, or dc. Figure 15, Figure 16, and Figure 17 illustrate these different isolation voltage waveforms.

A bipolar ac voltage environment is the most stringent. The goal of a 50-year operating lifetime under the ac bipolar condition determines the Analog Devices recommended maximum working voltage.

In the case of unipolar ac or dc voltage, the stress on the insulation is significantly lower. This allows operation at higher working voltages while still achieving a 50-year service life. The working voltages listed in Table 31 can be applied while maintaining the 50-year minimum lifetime, provided that the voltage conforms to either the unipolar ac or dc voltage cases. Any cross-insulation voltage waveform that does not conform to Figure 16 or Figure 17 must be treated as a bipolar ac waveform and the peak voltage must be limited to the 50-year lifetime voltage value listed in Table 31.

Note that the voltage presented in Figure 16 is shown as sinusoidal for illustration purposes only. It is meant to represent any voltage waveform varying between 0 V and some limiting value. The limiting value can be positive or negative, but the voltage cannot cross 0 V.



Figure 15. Bipolar AC Waveform



Figure 16. Unipolar AC Waveform



Figure 17. DC Waveform

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MS-012-AA
 CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
 (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
 REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

012407-A

Figure 18. 8-Lead Standard Small Outline Package [SOIC_N]
 Narrow Body (R-8)
 Dimensions shown in millimeters (inches)

ORDERING GUIDE

| Model ^{1, 2} | Number of Inputs, V _{DD1} Side | Number of Inputs, V _{DD2} Side | Maximum Data Rate (Mbps) | Maximum Propagation Delay, 5 V (ns) | Maximum Pulse Width Distortion (ns) | Temperature Range (°C) | Package Description | Package Option |
|-----------------------|---|---|--------------------------|-------------------------------------|-------------------------------------|------------------------|---------------------|----------------|
| ADuM3200ARZ | 2 | 0 | 1 | 150 | 40 | -40 to +105 | 8-Lead SOIC_N | R-8 |
| ADuM3200ARZ-RL7 | 2 | 0 | 1 | 150 | 40 | -40 to +105 | 8-Lead SOIC_N | R-8 |
| ADuM3200BRZ | 2 | 0 | 10 | 50 | 3 | -40 to +105 | 8-Lead SOIC_N | R-8 |
| ADuM3200BRZ-RL7 | 2 | 0 | 10 | 50 | 3 | -40 to +105 | 8-Lead SOIC_N | R-8 |
| ADuM3200CRZ | 2 | 0 | 25 | 45 | 3 | -40 to +105 | 8-Lead SOIC_N | R-8 |
| ADuM3200CRZ-RL7 | 2 | 0 | 25 | 45 | 3 | -40 to +105 | 8-Lead SOIC_N | R-8 |
| ADuM3200WARZ | 2 | 0 | 1 | 150 | 40 | -40 to +125 | 8-Lead SOIC_N | R-8 |
| ADuM3200WARZ-RL7 | 2 | 0 | 1 | 150 | 40 | -40 to +125 | 8-Lead SOIC_N | R-8 |
| ADuM3200WBRZ | 2 | 0 | 10 | 50 | 3 | -40 to +125 | 8-Lead SOIC_N | R-8 |
| ADuM3200WBRZ-RL7 | 2 | 0 | 10 | 50 | 3 | -40 to +125 | 8-Lead SOIC_N | R-8 |
| ADuM3200WCRZ | 2 | 0 | 25 | 45 | 3 | -40 to +125 | 8-Lead SOIC_N | R-8 |
| ADuM3200WCRZ-RL7 | 2 | 0 | 25 | 45 | 3 | -40 to +125 | 8-Lead SOIC_N | R-8 |
| ADuM3201ARZ | 1 | 1 | 1 | 150 | 40 | -40 to +105 | 8-Lead SOIC_N | R-8 |
| ADuM3201ARZ-RL7 | 1 | 1 | 1 | 150 | 40 | -40 to +105 | 8-Lead SOIC_N | R-8 |
| ADuM3201BRZ | 1 | 1 | 10 | 50 | 3 | -40 to +105 | 8-Lead SOIC_N | R-8 |
| ADuM3201BRZ-RL7 | 1 | 1 | 10 | 50 | 3 | -40 to +105 | 8-Lead SOIC_N | R-8 |
| ADuM3201CRZ | 1 | 1 | 25 | 45 | 3 | -40 to +105 | 8-Lead SOIC_N | R-8 |
| ADuM3201CRZ-RL7 | 1 | 1 | 25 | 45 | 3 | -40 to +105 | 8-Lead SOIC_N | R-8 |
| ADuM3201WARZ | 1 | 1 | 1 | 150 | 40 | -40 to +125 | 8-Lead SOIC_N | R-8 |
| ADuM3201WARZ-RL7 | 1 | 1 | 1 | 150 | 40 | -40 to +125 | 8-Lead SOIC_N | R-8 |
| ADuM3201WBRZ | 1 | 1 | 10 | 50 | 3 | -40 to +125 | 8-Lead SOIC_N | R-8 |
| ADuM3201WBRZ-RL7 | 1 | 1 | 10 | 50 | 3 | -40 to +125 | 8-Lead SOIC_N | R-8 |
| ADuM3201WCRZ | 1 | 1 | 25 | 45 | 3 | -40 to +125 | 8-Lead SOIC_N | R-8 |
| ADuM3201WCRZ-RL7 | 1 | 1 | 25 | 45 | 3 | -40 to +125 | 8-Lead SOIC_N | R-8 |

¹ Z = RoHS Compliant Part.

² W = Qualified for Automotive Applications.

AUTOMOTIVE PRODUCTS

The [ADuM3200W/ADuM3201W](#) models are available with controlled manufacturing to support the quality and reliability requirements of automotive applications. Note that these automotive models may have specifications that differ from the commercial models; therefore, designers should review the Specifications section of this data sheet carefully. Only the automotive grade products shown are available for use in automotive applications. Contact your local Analog Devices account representative for specific product ordering information and to obtain the specific Automotive Reliability reports for these models.

NOTES

NOTES

NOTES

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9